Electrochemical Synthesis of Binary and Ternary Refractory Compounds in the System Ti-Si-B from Chloride-Fluoride Melts

Sergei V. Devyatkin

Institute of General and Inorganic Chemistry, Palladin avenue 32/34, Kiev 252142, Ukraine

Reprint requests to Dr. S.V. D.; Fax: 38-044-4443070; E-mail: devyatkin@ionc.kar.net

Z. Naturforsch. **62a**, 524 – 528 (2007); received March 15, 2007

Presented at the EUCHEM Conference on Molten Salts and Ionic Liquids, Hammamet, Tunisia, September 16-22, 2006.

Electrochemical synthesis of binary and ternary compounds in the system Ti-Si-B from chloride-fluoride melts has been investigated by voltammetry and electrolysis. Electrochemical syntheses of titanium diboride, four titanium silicides ($TiSi_2$, TiSi, Ti_5Si_4 , Ti_5Si_3), silicon tetraboride and a new ternary compound, $Ti_5Si_3B_3$, have been found to be one-step processes. The stoichiometry of the deposited compounds has been found to correlate with the bulk concentration of Ti, Si and Bi ions in the melt.

Key words: Refractory Compounds; Electrochemical Synthesis; Molten Salts.